FAST RECOVERY RECTIFIERS

BYT52A(Z)---BYT52M(Z)

VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 1.4 A

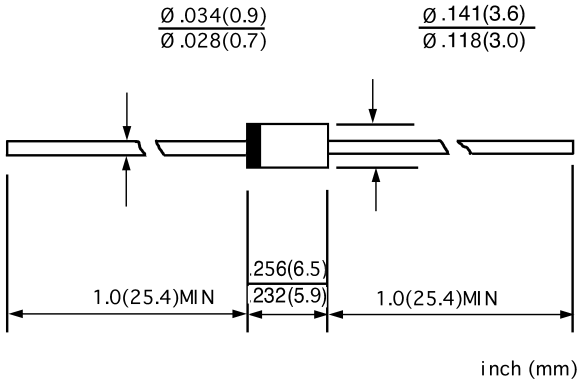
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon, Alcohol,Isopropanol and similar solvents

MECHANICAL DATA

- ◇ Case:JEDEC DO--15,molded plastic
- ◇ Terminals: Axial lead ,solderable per MIL- STD-202,Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces,0.39 grams
- ◇ Mounting position: Any

DO - 15



inch (mm)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,50Hz,resistive or inductive load. For capacitive load,derate by 20%.

		BYT 52A	BYT 52B	BYT 52D	BYT 52G	BYT 52J	BYT 52K	BYT 52M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	10	200	400	600	800	1000	V
Maximum average forw ard rectified current 9.5mm lead length, @T_A=75℃	$I_{F(AV)}$	1.4							A
Peak forw ard surge current 10ms single half-sine-w ave superimposed on rated load @T_J=125℃	I_{FSM}	50.0							A
Maximum instantaneous forw ard voltage @ 1.0A	V_F	1.3							V
Maximum reverse current @T_A=25℃	I_R	5.0							μA
at rated DC blocking voltage @T_A=100℃		100.0							
Maximum reverse recovery time (Note1)	t_{rr}	200							ns
Typical junction capacitance (Note2)	C_J	18							pF
Typical thermal resistance (Note3)	R_{qJA}	45							℃/W
Operating junction temperature range	T_J	-55 ---- + 150							℃
Storage temperature range	T_{STG}	-55 ---- + 150							℃

NOTE:1. Measured with I_F=0.5A, I_R=1A, I_{rr}=0.25A.

2. Measured at 1.0MHZ and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

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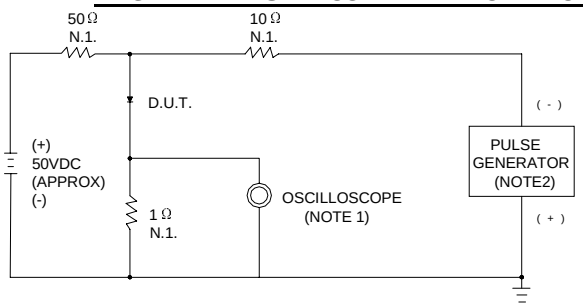
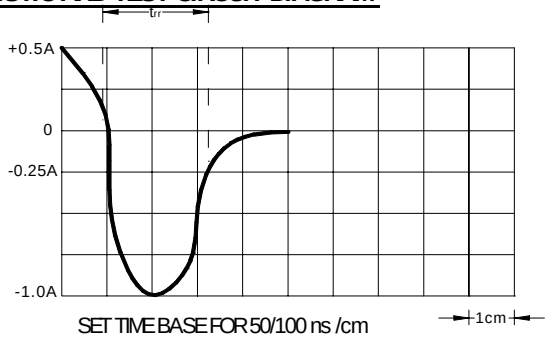
FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

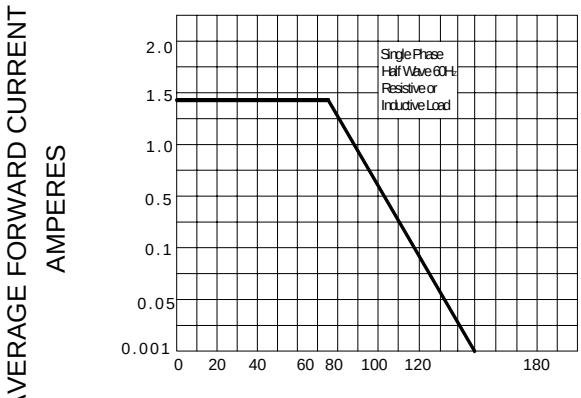




NOTES:1.RISE TIME=7ns MAX. INPUT IMPEDANCE=1MΩ.22pF
2.RISE TIME=10ns MAX. SOURCE IMPEDANCE=50Ω

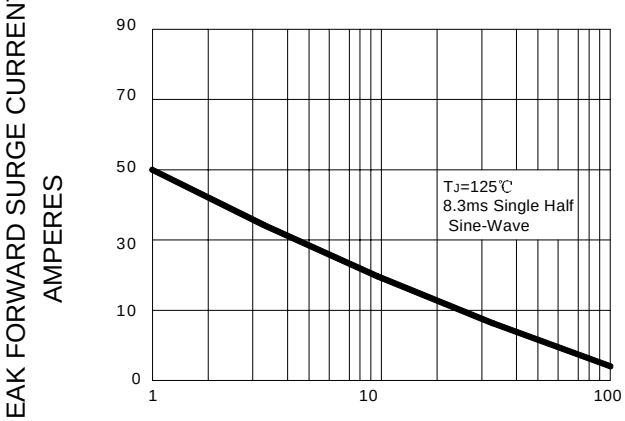
SET TIME BASE FOR 50/100 ns /cm

FIG.2 –FORWARD DERATING CURVE



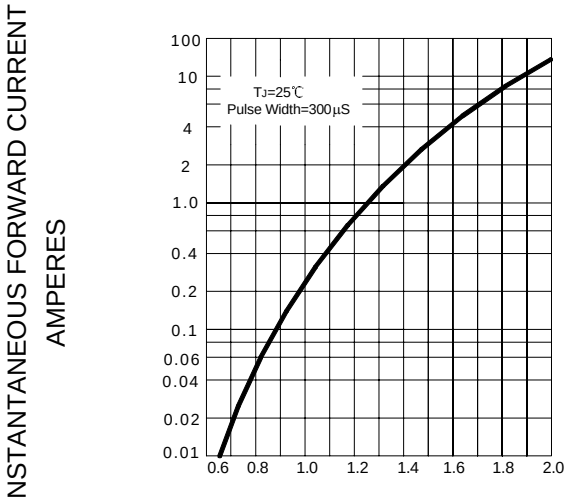
AMBIENT TEMPERATURE,℃

FIG.3 –PEAK FORWARD SURGE CURRENT



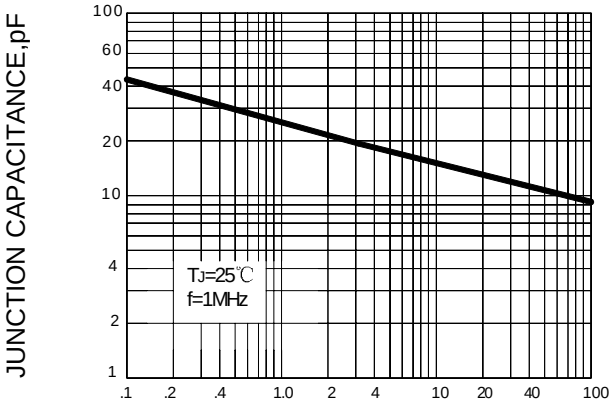
NUMBER OF CYCLES AT 60 Hz

FIG.4–TYPICAL FORWARD CHARACTERISTIC



INSTANTANEOUS FORWARD VOLTAGE,VOLTS

FIG.5–TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE,VOLTS